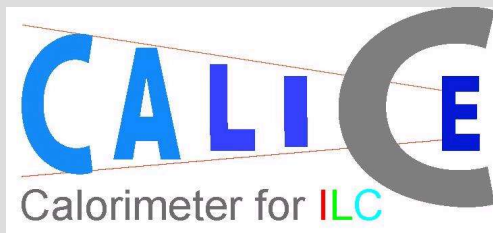


# Simulation of Monolithic Active Pixel Sensors for ILC ECAL

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# Outline

- **Introduction**
- **MAPS (Monolithic Active Pixel Sensors)**
  - Concepts
  - Design
- **Geometry modification**
- **Single e-/ $\mu$ - simulation**
  - Si sensitive thickness dependence
  - Cell size dependence
  - Incoming energy dependence
- **Summary of status**
- **Future prospects**

# Introduction

- **High granularity**
  - Small cells
    - **Digital Calorimetry**
- **Cost saving**
  - Using CMOS silicon
    - **Cheaper than high resistance pure silicon**

# MAPS concepts

- **Detecting individual particles after electromagnetic cascade shower by small cells**
- Result in measuring a single particle in a cell
  - Binary readout
    - Digital calorimetry
      - ➔ **High granularity**

# MAPS design

- Analogue design  
in Mokka
  - 1cm X 1cm cell
  - 500 $\mu$ m Si sensitive thickness
  - 500 $\mu$ m Si physical thickness
  - Analogue readout
- MAPS design
  - 50 $\mu$ m X 50 $\mu$ m cell
  - 15 $\mu$ m Si sensitive thickness
  - 500 $\mu$ m Si physical thickness
  - Binary readout

W thickness is the same with both cases.

# Geometry modification in Geant4 simulation

## Default

Upper PCB	800 $\mu\text{m}$
<b>Si Sensitive</b>	500 $\mu\text{m}$
Lower PCB	800 $\mu\text{m}$

## MAPS (test)

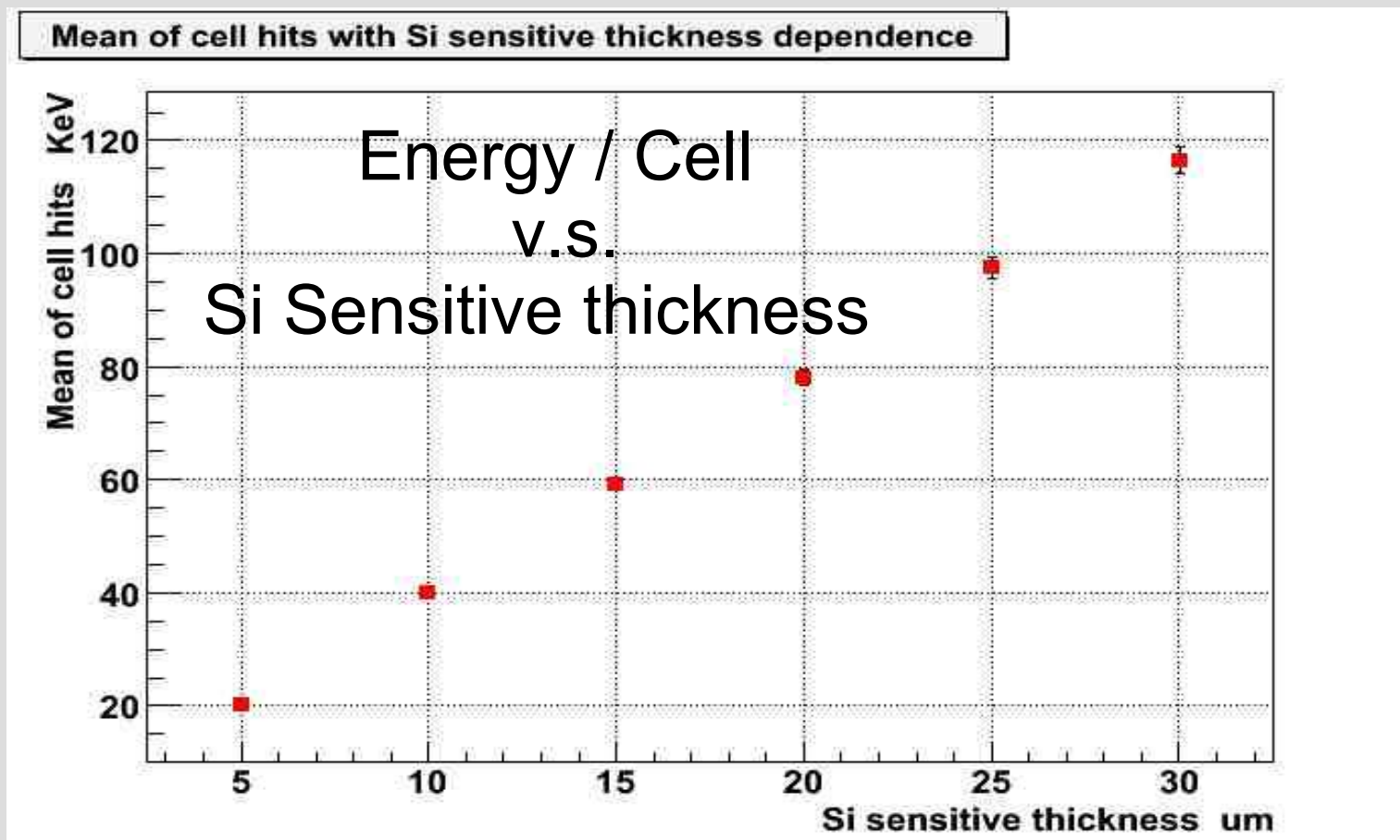
Upper PCB	800 $\mu\text{m}$
<b>Si Sensitive</b>	15 $\mu\text{m}$
Si Non-sensitive	485 $\mu\text{m}$
Lower PCB	800 $\mu\text{m}$

- Mokka 06-00
- Ecal02.cc (Geant4 ECAL driver) is modified.
- Geant4 Adaptive GUI output is fine.
- Energy deposit agreed with the expect.  
(i.e.  $15\mu\text{m}/500\mu\text{m} = 3.0\%$ )
- Layer position shift agreed with the expect.

# Single e- simulation (1.a)

## (Si sensitive thickness dependence)

20 GeV single electron (from IP to zenith with magnet on)  
Cell size is 1cm X 1cm

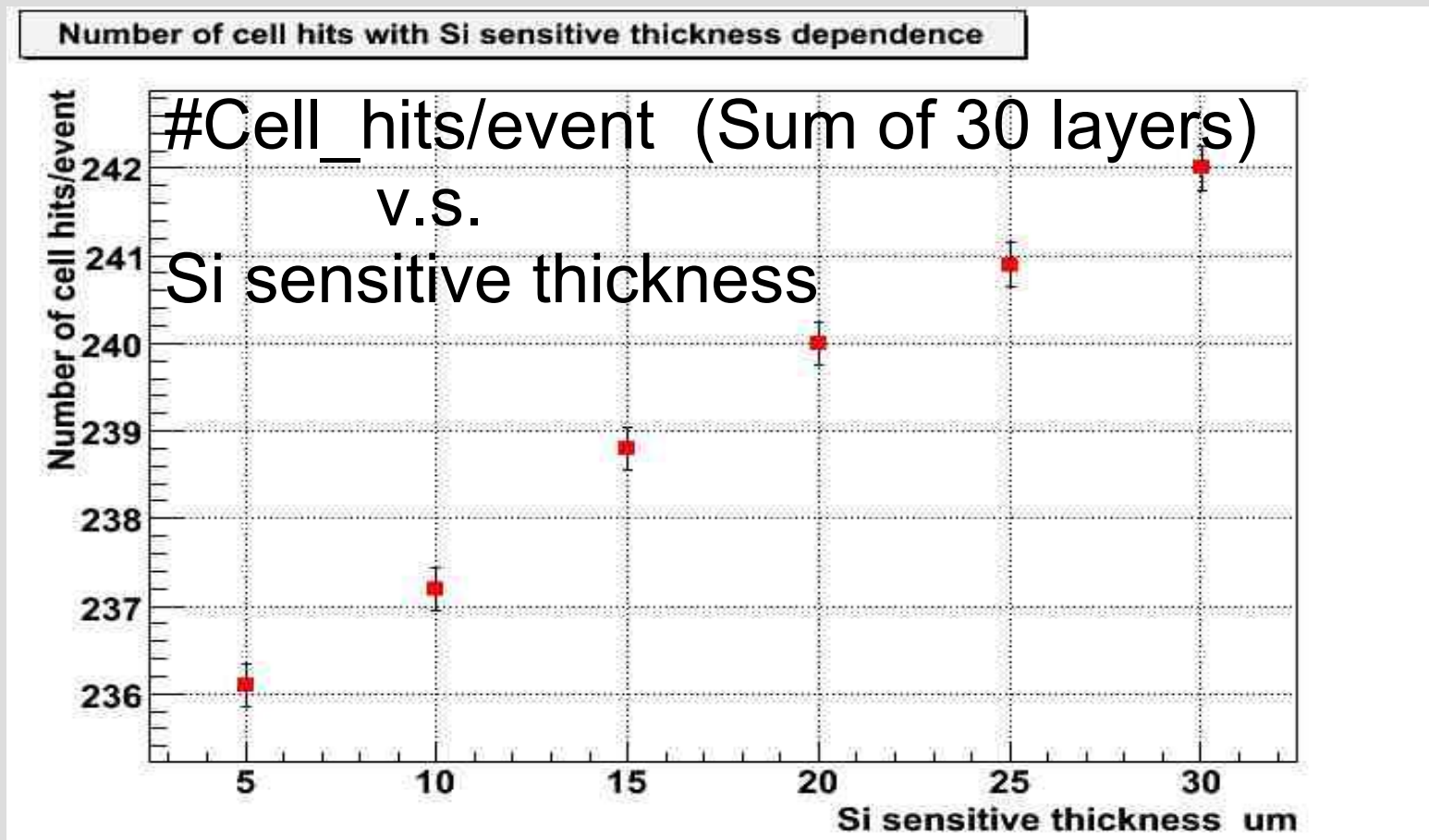


No threshold is applied for energy of cell hits

# Single e- simulation (1.b)

## (Si sensitive thickness dependence)

20 GeV single electron  
Cell size is 1cm X 1cm



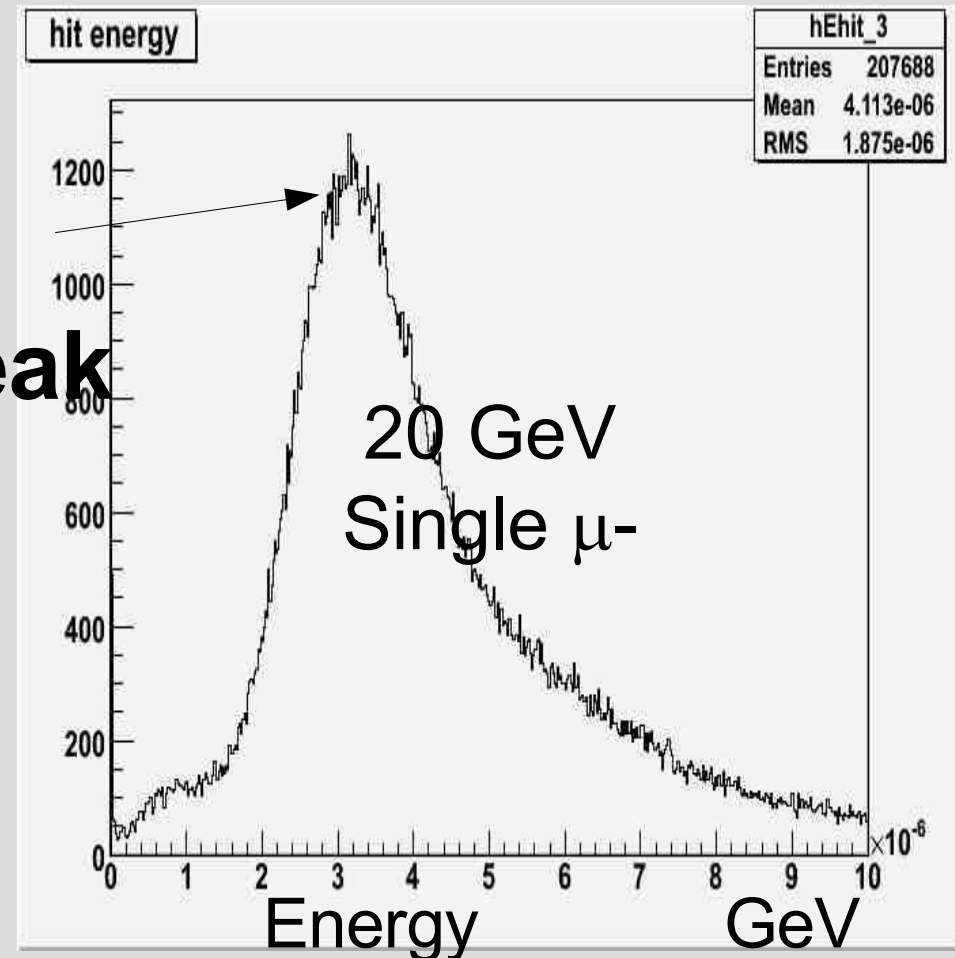
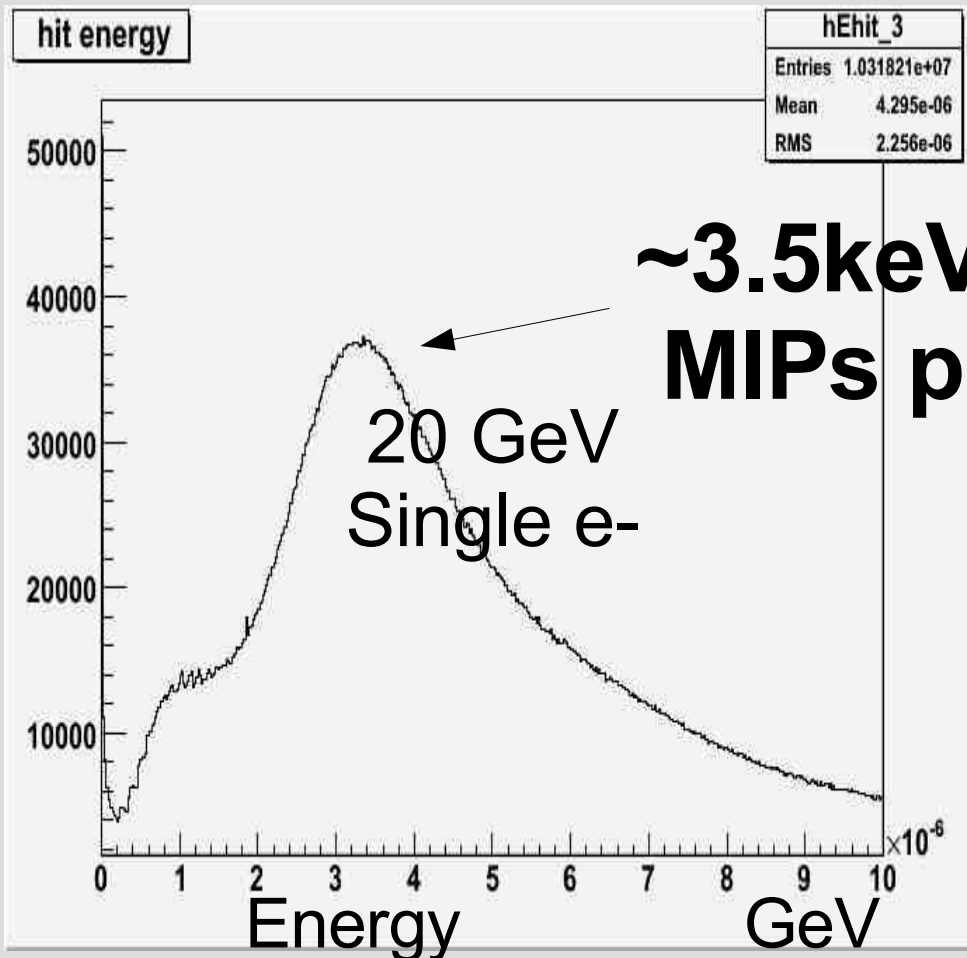
Only a few % dependence



# Single e-/μ- simulation (2)

## (Energy deposit of cell hits)

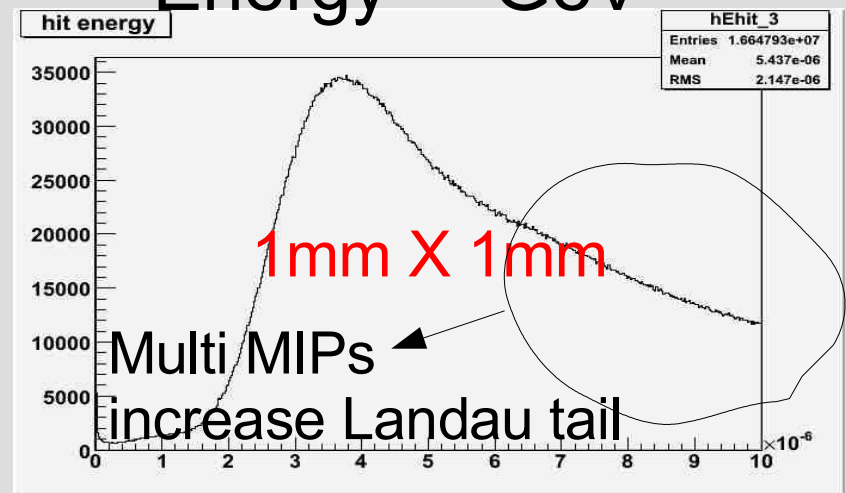
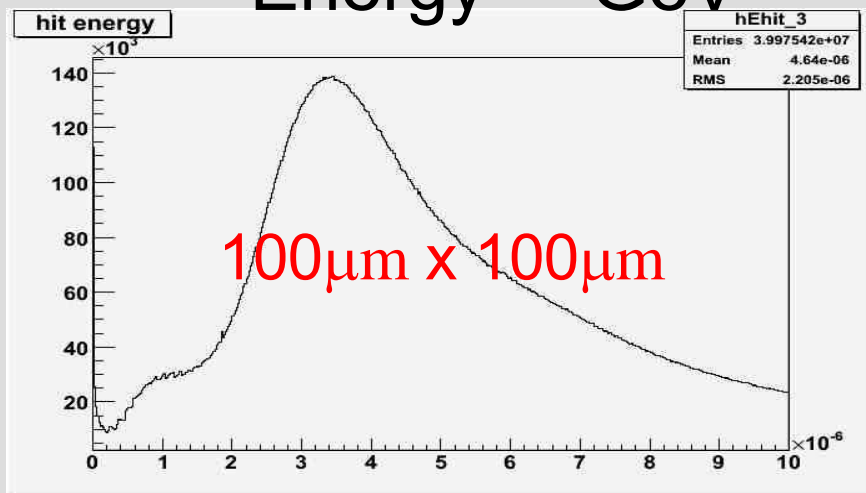
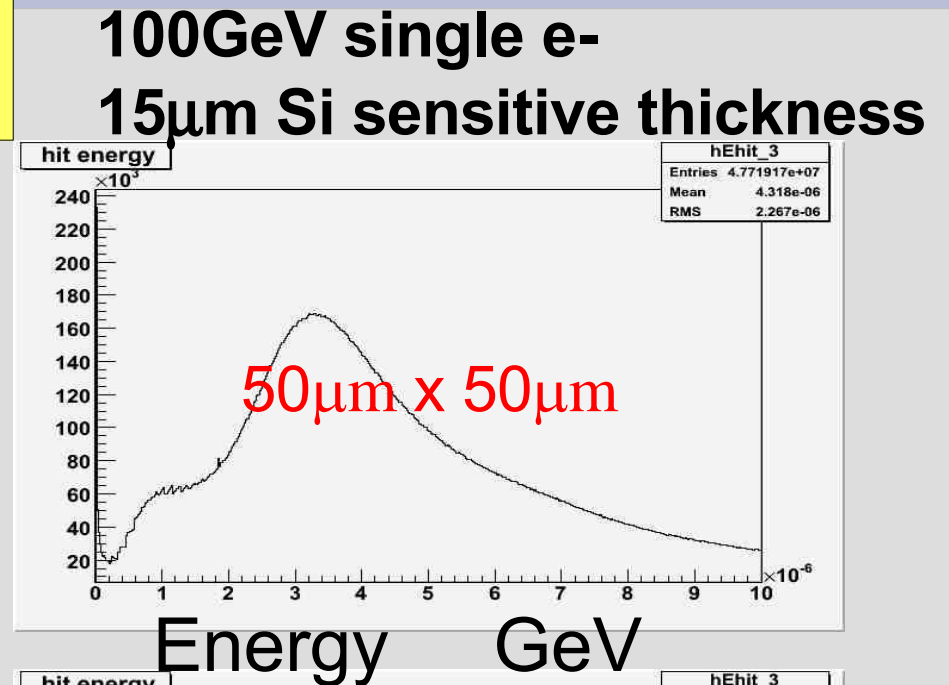
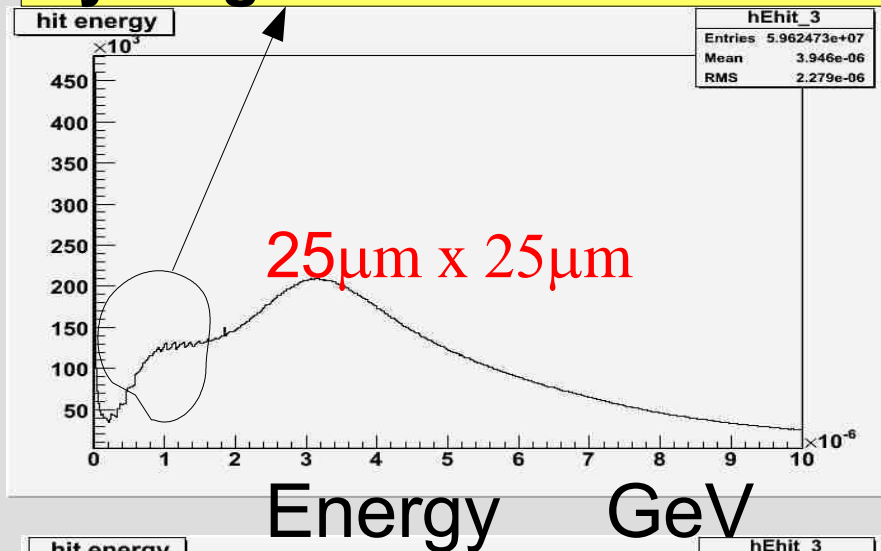
15μm Si sensitive thickness  
50μm X 50μm cell size



# Single e- simulation (3.a)

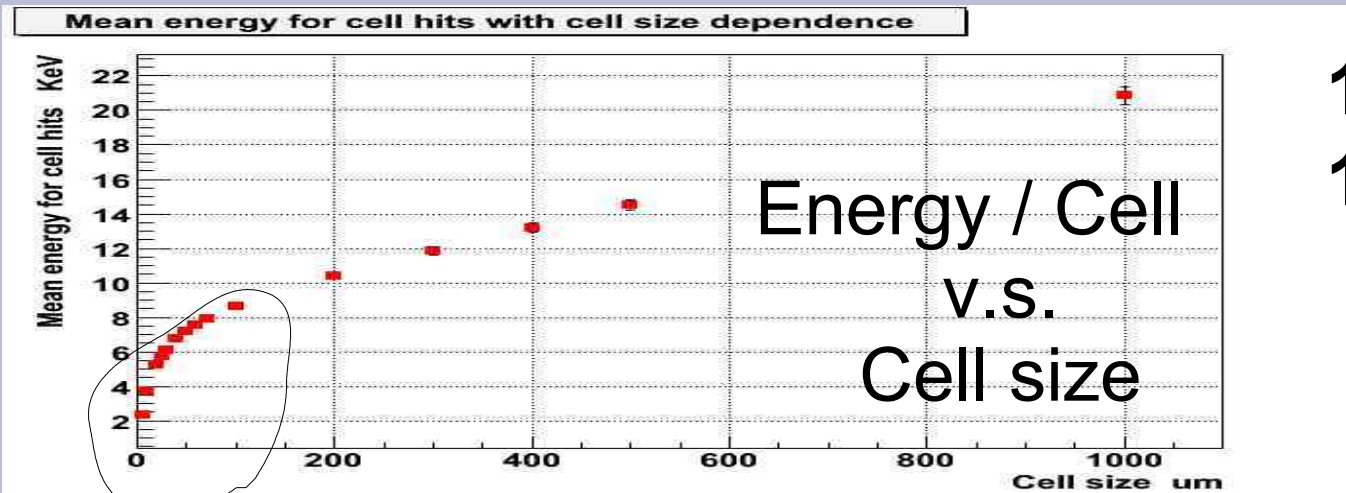
## (Cell size dependence)

Energy of one MIP is sharing by neighbour cell at boundary.

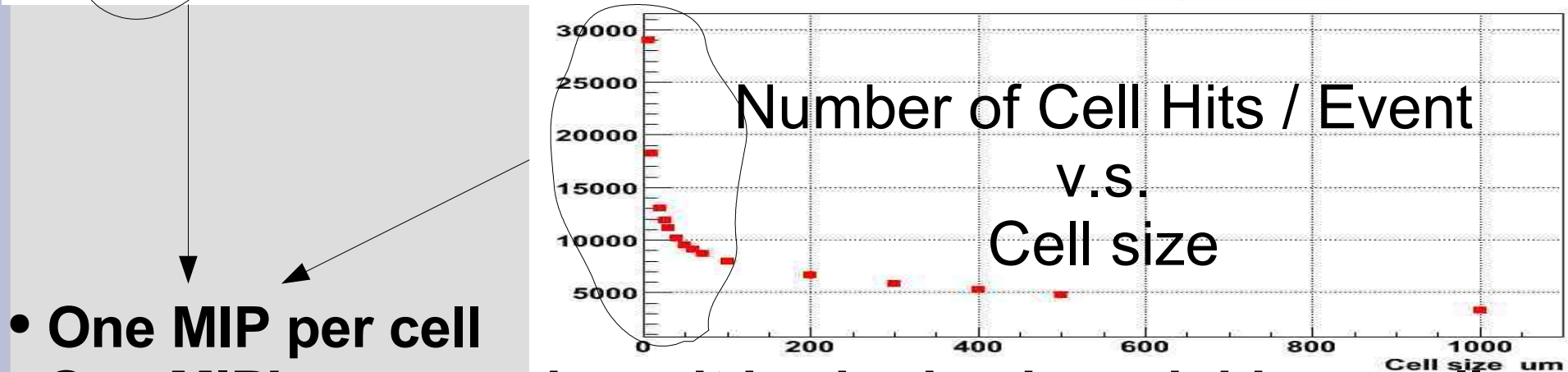


# Single e- simulation (3.b)

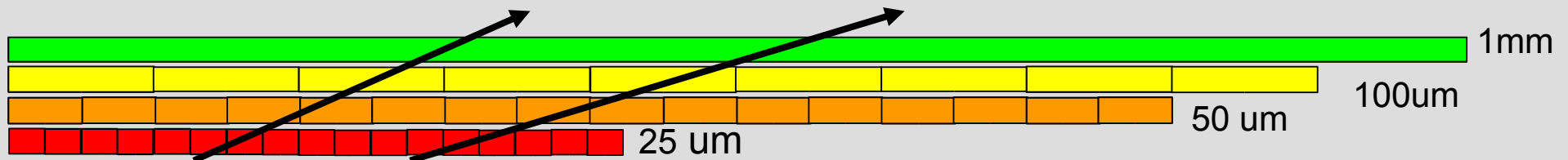
## (Cell size dependence)



100GeV e-  
15 $\mu$ m Si sensitive



- One MIP per cell
- One MIP's energy deposit is sharing by neighbour cell

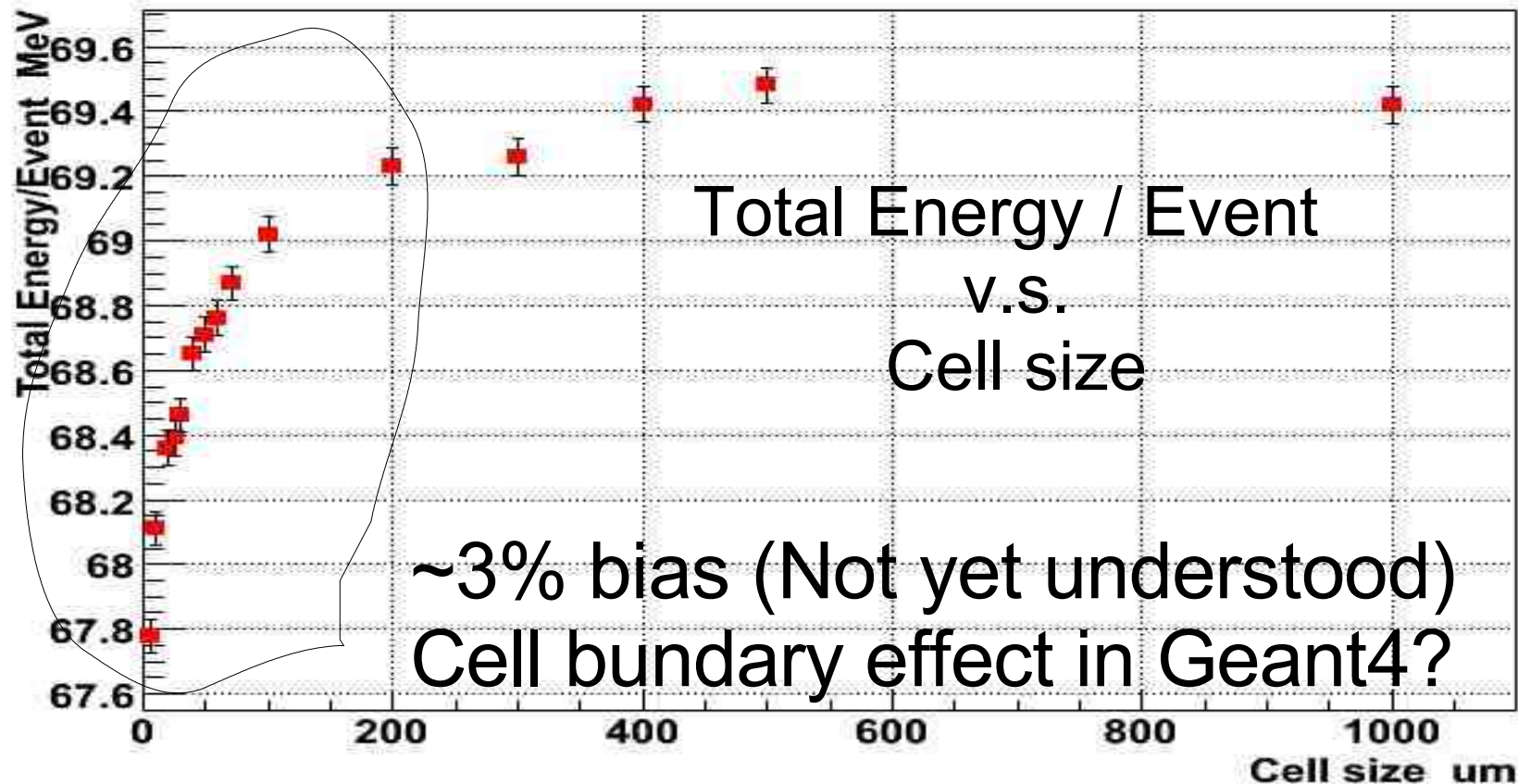


# Single e- simulation (3.c)

(Cell size dependence: consistency checks)

100GeV e-  
15 $\mu$ m Si sensitive

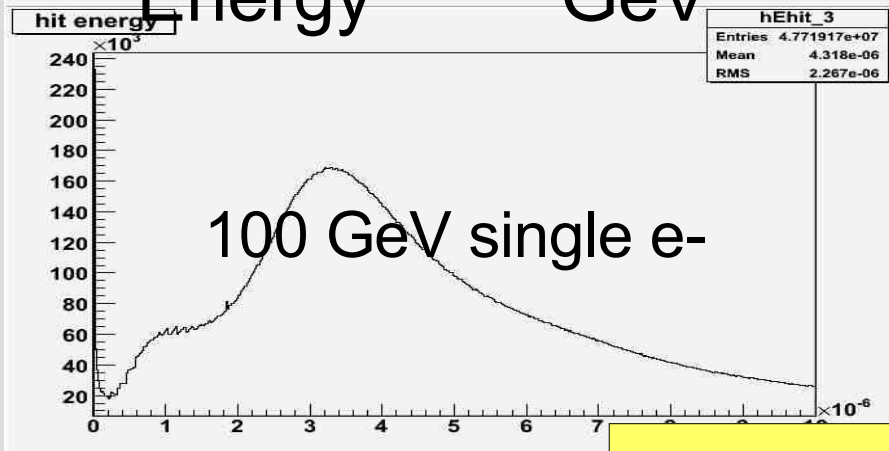
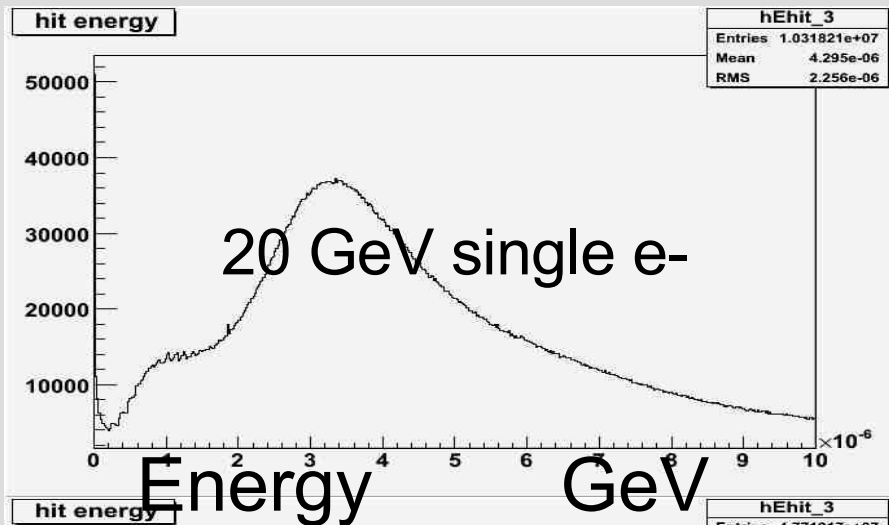
Total Energy per event with cell size dependence



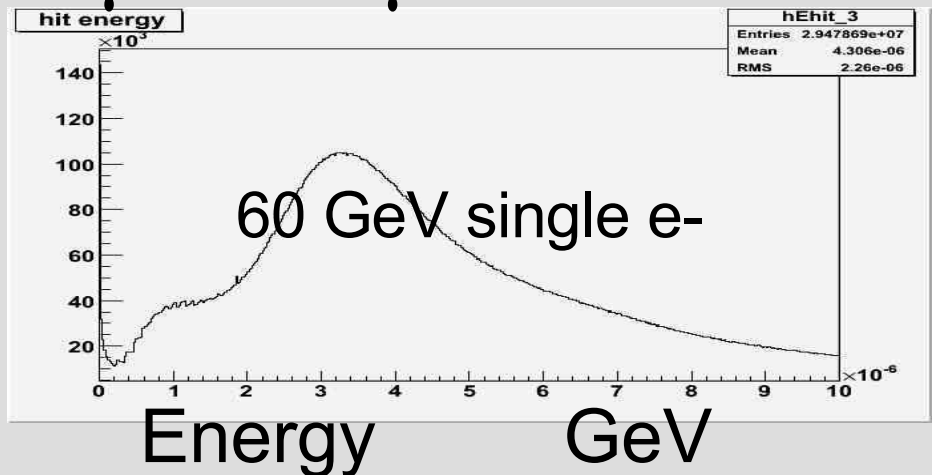
# Single e- simulation (4)

## (Incoming energy dependence)

Cell hits energy distributions



15 $\mu$ m Si sensitive thickness  
50 $\mu$ m X 50 $\mu$ m cell size



Mean of peak is independent of incoming energy.

→ **One MIP per cell**

→ Digital calorimetry

→ 50 $\mu$ m X 50 $\mu$ m cell is enough small

Cell hit number is proportional to incoming energy.

# Summary of status

- **MAPS geometry implementation is tested.**
- **Each cell has only one MIP in most case.**
- **Charge sharing by neighbour cell is seen.**
- **50 $\mu$ m X 50 $\mu$ m cell seems to be reasonable.**
- **Sensor level simulation is ongoing as well.**  
(Giulio Villani et al. -> please see Konstantin Stefanov's talk at calorimetry session.)

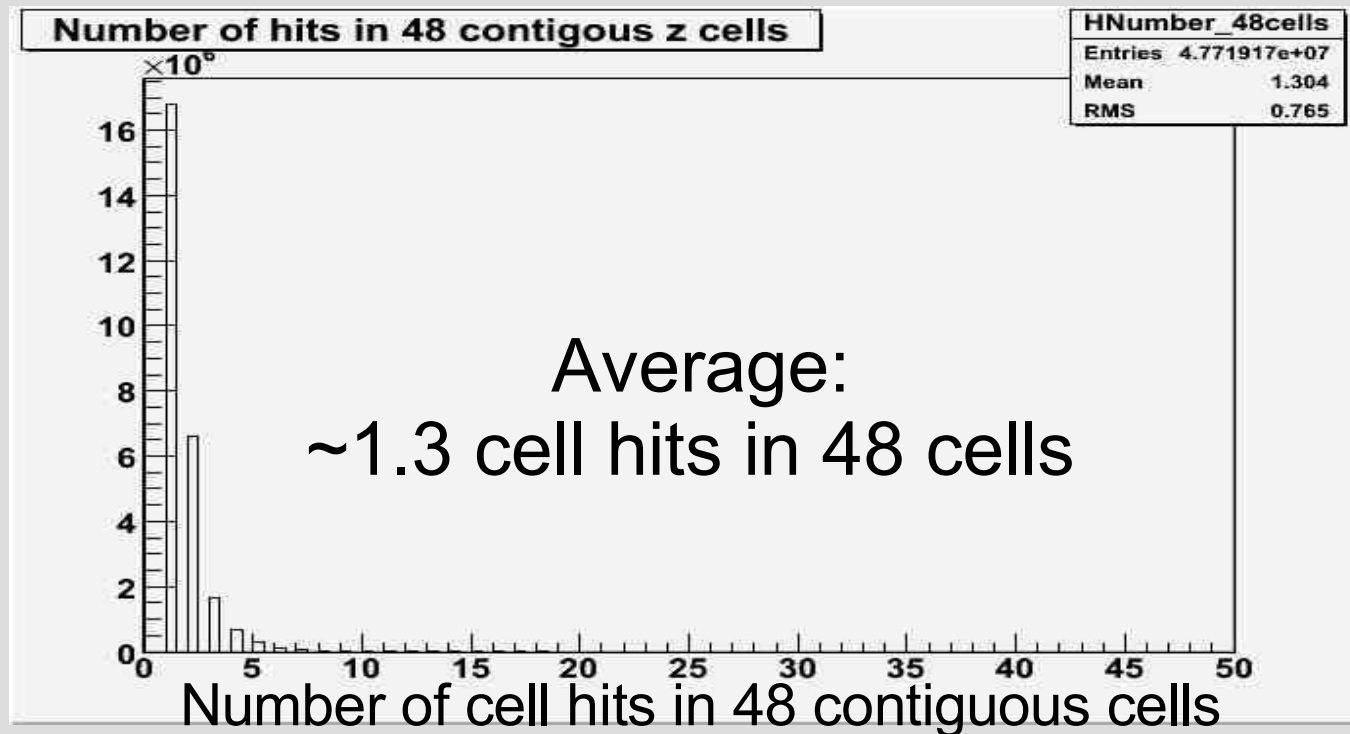
# Future Prospects

- **Implementing MAPS geometry in Mokka new version**
- **Resolution studies**
- **Clustering algorithm development**
  - It can be developed only with shower topology. (i.e. Each cell hit has identical energy.)
  - Sophisticated algorithm to save CPU time in this Tera pixel study.
- **Comparison with Data**
- **Physics events studies**

# Backup:

## Readout by 48 contiguous cells (Under study as one option)

100GeV single e-  
15 $\mu$ m Si sensitive thickness  
50 $\mu$ m X 50 $\mu$ m cell size



**Total energy also increased 30% compared with single cell.**